

HMIC[™] PIN Diode SP2T 10 Watt Switch for 0.05 - 6.0 GHz Higher Power Applications

Rev. V5

Features

- Exceptional Broadband Performance
- Suitable for Higher Power WiMax & WLAN Applications
- · Lower Loss:

Tx = 0.40 dB @ 3.8 GHz, 22mA Rx = 0.60 dB @ 3.8 GHz, 22mA

· Higher Isolation:

Rx-Tx = 21 dB @ 3.8 GHz Tx-Rx = 26 dB @ 3.8 GHz

- Higher RF Input Power = 10 W C.W. (Tx-Ant Port)
- Higher IIP3 = 65 dBm (Tx-Ant Port).
- Lower EVM (OFDM):

< 1.0% @ 8W Pin, (Tx-Ant Port)

- Lead-Free 3 mm 16-Lead PQFN Package
- 100% Matte Tin Plating over Copper
- Halogen-Free "Green" Mold Compound
- RoHS* Compliant and 260°C Reflow Compatible

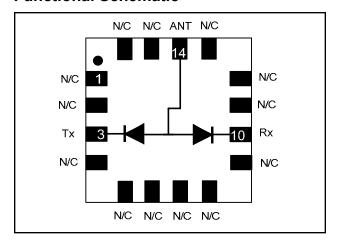
Description

MA-COM's MASW-000822-12770T is a Broadband, high linearity, common anode PIN diode SPDT switch in a lead-free 3 mm 16-lead PQFN package. The MASW-00822-1277OT is ideally suited for 0.05 - 6.0 GHz applications, including WiMax & WLAN.

This SP2T switch offers excellent isolation to loss ratio for both Tx and Rx states. The PIN diode provides exceptional 10 W C.W power handling coupled with 65 dBm IIP3 for maximum switch performance @ 3.8GHz.

This MASW-000822-1277OT incorporates a PIN diode die fabricated with M/A-COM's patented Silicon-Glass HMICTM process. This chip features two silicon pedestals embedded in a low loss, low dispersion glass. The diodes are formed on the top of each pedestal. The topside is fully encapsulated with silicon nitride and has an additional polymer passivation layer. These polymer protective coatings prevent damage and contamination during handling and assembly.

Functional Schematic



Pin Configuration ¹

Pin	Function	Pin	Function
1	N/C	9	N/C
2	N/C	10	Rx
3	Tx	11	N/C
4	N/C	12	N/C
5	N/C	13	N/C
6	N/C	14	Ant
7	N/C	15	N/C
8	N/C	16	N/C

 The exposed pad centered on the package bottom must be connected to RF and DC ground.

Ordering Information ²

Part Number	Package		
MASW-000822-1277OT	13 inch, 3000 piece reel		
MASW-000822-001SMB	Sample Board		

2. Reference Application Note M513 for reel size information.

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

Visit www.macomtech.com for additional data sheets and product information.

^{*} Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

North America Tel: 800.366.2266
 India Tel: +91.80.4155721
 Europe Tel: +353.21.244.6400
 China Tel: +86.21.2407.1588



HMIC[™] PIN Diode SP2T 10 Watt Switch for 0.05 - 6.0 GHz Higher Power Applications

Rev. V5

Electrical Specifications: $T_A = 25^{\circ}C$, $P_{IN} = 0$ dBm, $Z_0 = 50 \Omega$

Parameter	Conditions	Units	Min.	Тур.	Max.
Insertion Loss, Rx	Rx = +5.0 V @ +22 mA, Tx =+12V @ 0 mA 2.3 - 2.7 GHz 3.3 - 3.8 GHz 4.9 - 5.9 GHz	dB		0.55 0.60 0.80	0.70 0.75 0.90
Insertion Loss, Tx	Tx = +5.0 V @ +22 mA, Rx =+12V @ 0 mA 2.3 - 2.7 GHz 3.3 - 3.8 GHz 4.9 - 5.9 GHz	dB	_ _ _	0.35 0.40 0.50	0.45 0.55 0.60
Isolation, Tx to R _x	Tx = +5.0 V @ +22 mA, Rx =+12V @ 0 mA 2.3 - 2.7 GHz 3.3 - 3.8 GHz 4.9 - 5.9 GHz	dB	27.0 24.5 21.0	29.5 26.5 21.5	
Isolation, Rx to T _x	Rx = +5.0 V @ +22 mA, Tx =+12V @ 0 mA 2.3 - 2.7 GHz 3.3 - 3.8 GHz 4.9 - 5.9 GHz	dB	22.5 19.5 17.5	24.5 21.5 17.5	
Input Return Loss Tx	Tx = +5.0 V @ +22 mA, Rx =+12V @ 0 mA 2.3 - 2.7 GHz 3.3 - 3.8 GHz 4.9 - 5.9 GHz	dB		17 18 18	
Input Return Loss Rx	Rx = +5.0 V @ +22 mA, Tx =+12V @ 0 mA 2.3 - 2.7 GHz 3.3 - 3.8 GHz 4.9 - 5.9 GHz	dB		17 18 18	

Electrical Specifications: F = 3.5 GHz, T_A = 25°C, Z_0 = 50 $\Omega^{3,4,5}$

Parameter	Conditions	Units	Min.	Тур.	Max.
Tx Input P0.1dB	Tx = +5.0 V @ +22 mA, Rx =+12V @ 0 mA, Tx To Antenna	dBm	_	40	
Tx Input P1dB	Tx = +5.0 V @ +22 mA, Rx =+12V @ 0 mA, Tx To Antenna	dBm	_	45	_
Tx 2nd Harmonic	Tx = +5.0 V @ +22 mA, Rx =+12V @ 0 mA, Pin = + 30 dBm	dBc		-68	_
Tx 3rd Harmonic	Tx = +5.0 V @ +22 mA, Rx =+12V @ 0 mA, Pin = + 30 dBm	dBc		-84	_
Tx Input 3rd Order Intercept Point	Tx = +5.0 V @ +22 mA, Rx =+12V @ 0 mA, Pin = + 10 dBm F1 = 3.500 GHz, F2 = 3.510 GHz	dBm	_	65	_
Tx C.W. Input Power	Tx = +5.0 V @ +22 mA, Rx =+12V @ 0 mA, F= 4.0 GHz	dBm	_	_	40
Rx C.W. Input Power	Rx = +5.0 V @ +22 mA, Tx =+12V @ 0 mA, F= 4.0 GHz	dBm			33
Tx EVM (OFDM)	Tx = +5.0 V @ +22 mA, Rx =+12V @ 0 mA, Pin = +39 dBm	%	_	0.8	_
Tx EVM (OFDM)	Tx = +5.0 V @ +22 mA, Rx =+12V @ 0 mA, Pin = +40 dBm	%		1.2	
Tx RF Switching Speed	(10-90% RF Voltage) Tx = +5.0 V@ +22 mA, Rx =+12V @ 0 mA 1MHz Rep Rate in Modulating Mode	ns	_	<500	_

- 3. Data taken at device RF leads.
- 4. Typical PIN diode forward voltage = +0.8 V @ 10 mA, +0.85 V @22 mA.
- 5. Typical PIN diode reverse voltage = +12.0 V

North America Tel: 800.366.2266
 India Tel: +91.80.4155721
 Europe Tel: +353.21.244.6400
 China Tel: +86.21.2407.1588
 Visit www.macomtech.com for additional data sheets and product information.

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.



HMIC[™] PIN Diode SP2T 10 Watt Switch for 0.05 - 6.0 GHz Higher Power Applications

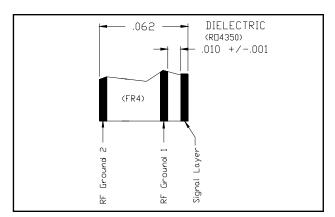
Rev. V5

Absolute Maximum Ratings ⁶

0 T_A = +25 °C (unless otherwise specified)

Parameter	Absolute Maximum		
Forward Current	+ 100 mA		
Reverse Voltage	-100 V		
Operating Temperature	-40 °C to +85 °C		
Storage Temperature	-55 °C to +150 °C		
Junction Temperature	+175 °C		
Tx Incident C.W. Power	10 W C.W.		
Tx Peak Incident Power	20 W, 3 μS P.W., 1% Duty		
Rx Incident C.W. Power	2 W C.W.		

Cross Section View of M/A-Com PCB

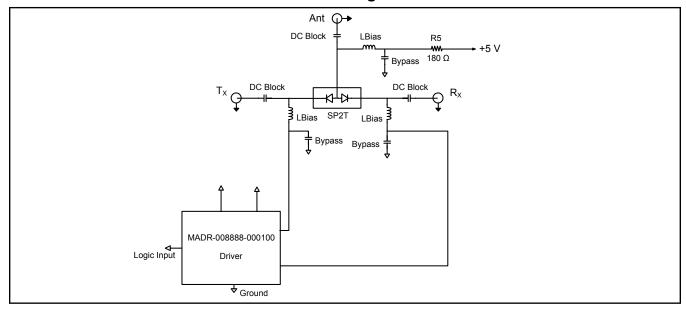


6. Exceeding these limits may cause permanent damage.

D.C. Bias to RF Truth Table

RF State	TTL & D.C. Bias Conditions	Voltage at Common Anode
Low Loss Tx-Ant & Isolation Tx-Rx	TTL = 1 + 5V @ 22 mA (Tx), + 12V @ 0 mA (Rx)	+ 0.9 V
Low Loss Ant-Rx & Isolation Rx-Tx	TTL = 0 + 5V @ 22 mA (Rx), + 12V @ 0 mA (Tx)	+ 0.9 V

Driver and SP2T Schematic with Positive Voltage 7,8,9,10,11



- 7. Forward Bias Diode Voltage, ΔVf @ 22 mA = + 0.9 V.
- 8. Reverse Bias Diode = | (+12 V +0.9 V) | = | 11.1 | V.

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology

and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed. North America Tel: 800.366.2266
 India Tel: +91.80.4155721
 China Tel: +86.21.2407.1588

Visit www.macomtech.com for additional data sheets and product information.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

3

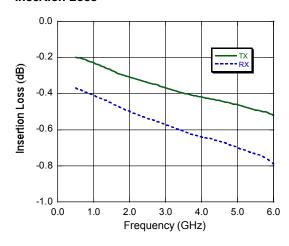


HMIC[™] PIN Diode SP2T 10 Watt Switch for 0.05 - 6.0 GHz Higher Power Applications

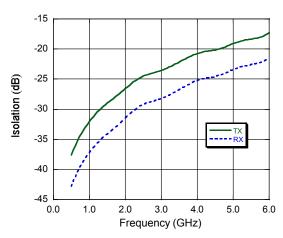
Rev. V5

Typical Performance Curves: $T_A = 25^{\circ}C$, $Z_0 = 50 \Omega$

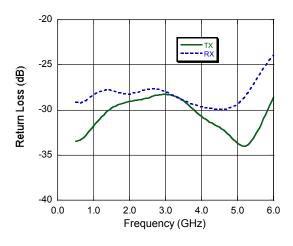
Insertion Loss



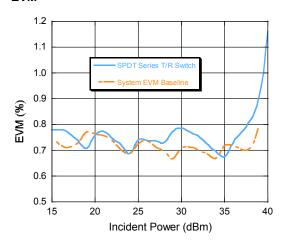
Isolation



Tx and RX Return Loss



EVM

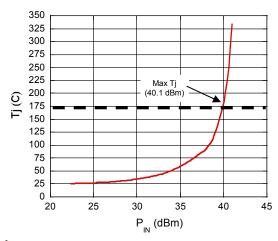




HMIC™ PIN Diode SP2T 10 Watt Switch for 0.05 - 6.0 GHz Higher Power Applications

Rev. V5

Tx Diode Junction Temperature vs. C.W. Input Power @ 4.0 GHz, $Tj = 175 ^{\circ}\text{C}$



This device is not for saturation power application. Exceeding power dissipation maximum rating might result in device failure.

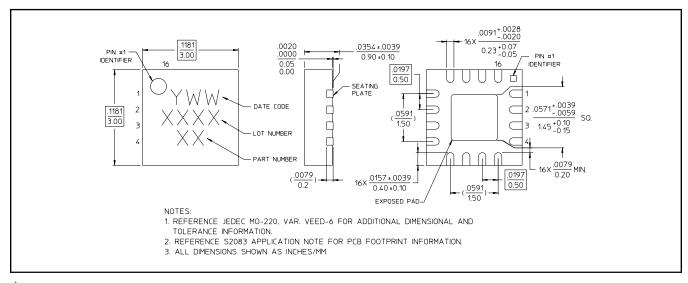
Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

These devices are rated at Class 1B Human Body. Proper ESD control techniques should be used when handling these devices.

Lead-Free 3 mm 16-Lead PQFN[†]



[†]Reference Application Note S2803 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements.

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not quaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology

Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

North America Tel: 800.366.2266 Europe Tel: +353.21.244.6400 • India Tel: +91.80.4155721 • China Tel: +86.21.2407.1588

Visit www.macomtech.com for additional data sheets and product information.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.